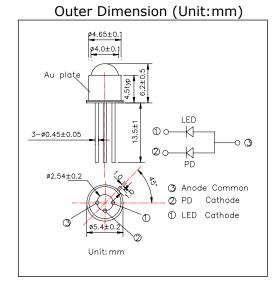
## L780/PD010-40D32-I

Metal Can Sealed PD Monitoring High Power LED

L780/PD010-40D32-I consists of a GaAlAs LED 780nm and a Si-PD mounted on TO-18 stem at anode common and hermetically sealed with a glass ball lens can. It is designed to monitor reflected light through detector for controlling its own output power.

## <Specifications>

- 1. Product Name: LED Lamp with PD Monitor
- 2. Type Number: L780/PD010-40D32-I
- 3. Chip:
  - Chip Material: GaAlAs and Si(PIN)
  - Peak Wavelength: 780nm
- 4.Package
  - Stem: TO-18
  - Lens: Φ5 Glass Ball Lens
  - Can: Metal Can (Gold Plate)



Absolute Maximum Ratings[Ta=25°C]								
Device	Item	Symbol	Maximum Rated Value	Unit				
LED	Power Dissipation	PD	200	mW				
LED	Forward Current	IF	100	mA				
LED	Pulse Forward Current*	IFP	500	mA				
LED	Reverse Voltage	VR	5	V				
PD	Reverse Voltage	VR	100	V				
	Operating Temperature	TOPR	-30 ~ +85	°C				
	Storage Temperature	TSTG	-30 ~ +100	°C				
	Soldering Temperature**	TSOL	260	°C				

\* Duty=1% and tw=10us

\*\* Soldering condition must be completed within 3 seconds at 260°C

Electro-Optical Characteristics [Ta=25°C]										
Item	Symbol	Condition	Minimum	Typical	Maximum	Unit				
Forward Voltage	VF	IF=50mA		1.8	2.0	V				
Reverse Current	IR	VR=5V			10	uA				
Total Radiated Power*	PO	IF=50mA		12.0		mW				
Radiant Intensity**	IE	IF=50mA		40.0		mW/sr				
Peak Wavelength	λP	IF=50mA	760	780	800	nm				
Half Width	Δλ	IF=50mA		35		nm				
Viewing Half Angle	θ1/2	IF=50mA		±15		deg				
Rise Time	tr	IF=50mA		80		ns				
Fall Time	tf	IF=50mA		80		ns				
Output Current	IL	VR=0V		300		uA				
Dark Current	ID	VR=10V			10	nA				

\* Measured by Photodyne #500

\*\* Measured by Tektronix J-6512

Marubeni America Corporation | 3945 Freedom Circle, Suite 1000, Santa Clara, CA95054 Tel: 408-330-0650 | Fax: 408-330-0655 | Email: sales@tech-led.com